



# **IRF7907TRPBF Information**



For Reference Only

Part Number IRF7907TRPBF
Manufacturer Infineon Technologies

Category Discrete Semiconductor Products
Transistors - FETs, MOSFETs - Arrays

**Description** MOSFET 2N-CH 30V 9.1A/11A 8-SOIC

Package 8-SOIC (0.154", 3.90mm Width)

For the pricing/inventory/lead time, please contact

us

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# **IRF7907TRPBF Specifications**

Manufacturer Part NumberIRF7907TRPBFManufacturerInfineon TechnologiesCategoryDiscrete Semiconductor ProductsTransistors - FETs, MOSFETs - ArraysPackage8-SOIC (0.154", 3.90mm Width)SeriesHEXFET?FET Type2 N-Channel (Dual)FET FeatureLogic Level GateDrain to Source Voltage (Vdss)30VCurrent - Continuous Drain (Id) @ 25°C9.1A, 11ARds On (Max) @ Id, Vgs16.4 mOhm @ 9.1A, 10VVgs(th) (Max) @ Id2.35V @ 25μAGate Charge (Qg) (Max) @ Vgs10nC @ 4.5VInput Capacitance (Ciss) (Max) @ Vds850pF @ 15VPower - Max2WOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeSurface MountPackage / Case8-SOIC (0.154", 3.90mm Width)Supplier Device Package8-SO		
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Supplier Device Package 8-SO	Package / Case	8-SOIC (0.154", 3.90mm Width)
	Supplier Device Package	8-SO
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#### **IRF7907TRPBF Guarantees**



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## **IRF7907TRPBF Payment Methods**





















## **IRF7907TRPBF Shipping Methods**













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